



PATENT
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF : TECHNOLOGIES LTRIM INC.
FOR : METHOD FOR MODIFYING THE
IMPEDANCE OF SEMICONDUCTOR
DEVICES USING A FOCUSED HEATING
SOURCE
SERIAL NO. : 10/631,825
FILED : August 1, 2003
GROUP ART : 3765
ATTORNEY DOCKET NO. : 06042-006-US-02

Montreal, Quebec, Canada
December 18, 2003

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner
of Patents and Trademark
Washington, D.C. 20231


Dear Sir:

The applicant hereby submits the attached list of pertinent prior art on form PTO/SB/08A.

The applicant has also attached a copy of the references listed.

The applicant believes that no fees are due, however if any fees whatsoever are necessary with respect to the present application, the United States Patent and Trademark Office is hereby authorized to charge any such fee to our **Deposit Account no. 02-3980.**

Respectfully submitted,


Ronald S. Kosie, reg. No. 28,814
BROUILLETTE KOSIE PRINCE
1100 René-Lévesque Boulevard West 25th Floor
Montreal, Quebec, H3B 5C9 CANADA

Encls : Form PTO/SB/08A
Copy of listed prior art
Confirmation receipt postcard



Substitute for form 149A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Application Number	10/631,825
		Filing Date	August 1, 2003
		First Named Inventor	LACOURSE, Alain
		Art Unit	3765
		Examiner Name	
Sheet 1	of 1	Attorney Docket Number	06042-006-US-02

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.	Document Number Number – Kind Code	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Documents	Pages, Columns, Line, Where Relevant Passages or Relevant Figures Appear
	A	6,329,272	11-11-01		
	B	5,110,758	05-05-92		
	C				

FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No.	Foreign Patent Document Country – Number – Kind Code	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Documents	Pages, Columns, Line, Where Relevant Passages or Relevant Figures Appear	T
	D	EP 0 472 331	02-26-92			
	E	JP 59100646	05-21-84			

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS). Title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number (s), publisher, city and/or country where published.	T
		Parker D L et al: "Polysilicon Resistor trimming by laser link making" IEEE Transactions on semiconductor manufacturing, IEEE inc. New York, US, vol 3, no. 2, 1 may 1990 pages 80-83,	

Examiner Signature		Date Considered	
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